Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
Between 0.150 inches and	0.260 inches
Terminal Length:	
0.500 inches	
Overall Diameter:	
Between 0.335 inches and	0.370 inches
Electrode Internally-elect	trically Connected To Case:
Collector	
Component Name And Q	uantity:
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter	:
Between 0.190 inches and	0.210 inches
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts P	er Characteristic:
60.0 collector to base volta	age/static/emitter open all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 5.0
emitter to base voltage, st	atic, collector open all transistor
Current Rating Per Chara	acteristic:
50.00 milliamperes source	cutoff current all transistor
Power Rating Per Charac	steristic:
0.6 watts small-signal input	t power, common-collector preset all transistor
Maximum Operating Tem	npurature Per Measurement Point:
200.0 degrees celsius junc	tion
Special Features:	
All transistor junction patter	rn arrangement: pnp
Test Data Document:	
81349-mil-s-19500 specific	cation (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commerc	cial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and perform	nance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quan	
6 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/336 gov	vernment specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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